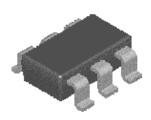
## P-Channel 40-V (D-S) MOSFET

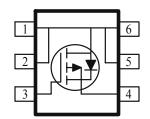
These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low $r_{DS(on)}$ provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe TSOP-6 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY				
$V_{DS}(V)$ $r_{DS(on)}(\Omega)$ $I_{D}(A)$				
-40	$0.070 @ V_{GS} = -10V$	-4.4		
-40	$0.090 @ V_{GS} = -4.5V$	-3.9		





ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)					
Parameter			Maximum	Units	
Drain-Source Voltage			-40	V	
Gate-Source Voltage			±20	V	
	$T_A=25^{\circ}C$	ī	-4.0		
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$			A	
Pulsed Drain Current <sup>b</sup>			±20		
Continuous Source Current (Diode Conduction) <sup>a</sup>			-1.7	A	
D D: : a	$T_A=25^{\circ}C$	D	2.0	W	
Power Dissipation <sup>a</sup>	$T_A = 25^{\circ} \text{C}$ $T_A = 70^{\circ} \text{C}$	T D	1.3	vv	
Operating Junction and Storage Temperature Range		$T_{J}, T_{stg}$	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
M · I · · · a	$t \le 5 \sec$	D	62.5	°C/W	
Maximum Junction-to-Ambient <sup>a</sup>	Steady state	$R_{THJA}$	110	°C/W	

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## Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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Dawamatau	C11	T	Limits			TT*4	
Parameter	Symbol	<b>Test Conditions</b>	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	-1				
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			±100	nA	
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = -32 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA	
Zelo Cate Voltage Diam Current	1088	$V_{DS} = -32 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			-5	uA	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-20			A	
D : C O D : A		$V_{GS} = -10 \text{ V}, I_D = -4.4 \text{ A}$			70		
Drain-Source On-Resistance <sup>A</sup>	fDS(on)	$V_{GS} = -4.5 \text{ V}, I_D = -3.9 \text{ A}$			90	mΩ	
Forward Tranconductance <sup>A</sup>	gs	$V_{DS} = -5 \text{ V}, I_D = -4.4 \text{ A}$		10		S	
Diode Forward Voltage	$V_{\mathrm{SD}}$	$I_S = 1.3 \text{ A}, V_{GS} = 0 \text{ V}$		-0.8		V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_{g}$	$V_{DS} = -20 \text{ V}, V_{GS} = -10 \text{ V},$		6.4		nC	
Gate-Source Charge	$Q_{gs}$	$I_D = -44 \text{ A}$		1.9			
Gate-Drain Charge	Qgd	ID —		2.5			
Switching					•		
Turn-On Delay Time	t <sub>d(on)</sub>			7			
Rise Time	$t_{\rm r}$	$V_{DD}^{}=-20$ V, $R_L^{}=6~\Omega$ , $I_D=-1~A,$		10		ns	
Turn-Off Delay Time	td(off)	$V_{GEN} = -10 \text{ V}$		30		115	
Fall-Time	$t_{\mathrm{f}}$			22			

## Notes

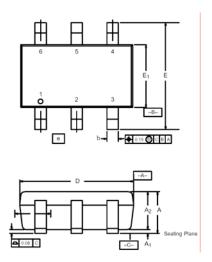
- a. Pulse test:  $PW \le 300us duty cycle \le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

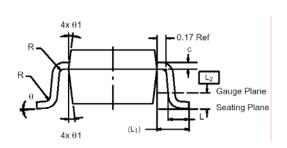
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## Package Information

TSOP-6: 6LEAD





	MILLIMETERS INCHES				;	
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.91	-	1.10	0.036	_	0.043
A <sub>1</sub>	0.01	-	0.10	0.0004	-	0.004
A <sub>2</sub>	0.84	_	1.00	0.033	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
С	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
E	2.70	2.85	2.98	0.106	0.112	0.117
E <sub>1</sub>	1.55	1.65	1.70	0.061	0.065	0.067
е	1.00 BSC			(	0.0394 BSC	;
L	0.35	-	0.50	0.014	-	0.020
L <sub>1</sub>	0.60 Ref				0.024 Ref	
L <sub>2</sub>	0.25 BSC				0.010 BSC	
R	0.10	_	_	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
$\theta_1$	7° Nom				7° Nom	